

## Dual, 200mA Output, Low Noise, High PSRR Low-Dropout Linear Regulators

## FEATURES

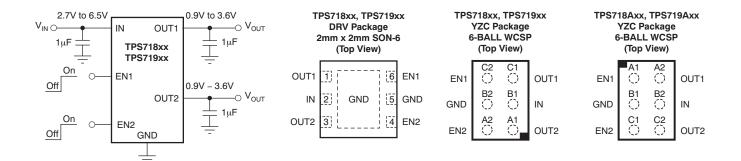
- Dual, 200mA High-Performance LDOs •
- Low Total Quiescent Current: 90µA with Both LDOs Enabled
- Low Noise: 70µV<sub>RMS</sub>/V
- Active Output Pulldown (TPS719xx) •
- Independent Enables for Each LDO
- PSRR: 65dB at 1kHz, 45dB at 1MHz
- Available in Multiple Fixed-Output Voltage . Combinations from 0.9V to 3.6V Using Innovative Factory EEPROM Programming
- Fast Start-Up Time: 160µs .
- **Over-Current, Over-Temperature and** • **Under-Voltage Protection**
- Low Dropout: 230mV at 200mA
- Stable with 1µF Ceramic Output Capacitor .
- Available in  $2mm \times 2mm$  SON-6 and 6-Ball WCSP Packages

## DESCRIPTION

The TPS718xx and TPS719xx families of low-dropout (LDO) regulators offer a high power-supply rejection ratio (PSRR), low noise, fast start-up, and excellent line and load transient responses while consuming a very low 90µA (typical) at no load ground current with both LDOs enabled. The TPS719xx also provides an active pulldown circuit to quickly discharge output loads. The TPS718xx and TPS719xx are stable with ceramic capacitors and use an advanced BiCMOS fabrication process to yield a typical dropout voltage of 230mV at 200mA output loads. The TPS718xx and TPS719xx also use a precision voltage reference and feedback loop to achieve 3% overall accuracy over all load, line, process, and temperature variations. Both families of devices are fully specified from  $T_J = -40^{\circ}C$ to +125°C and are offered in 2mm × 2mm SON-6 and 6-ball Wafer Chip-Scale (WCSP) packages that are ideal for applications such as mobile handsets and WLAN that require good thermal dissipation while maintaining a very small footprint.

## APPLICATIONS

- **Digital Cameras and Camera Modules**
- **Cellular Camera and TV Phones**
- Wireless LAN, Bluetooth®
- **Handheld Products**



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Typical Application Circuit

## TPS718xx TPS719xx



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### ORDERING INFORMATION<sup>(1)</sup>

PRODUCT	V <sub>OUT</sub> <sup>(2)(3)</sup>
TPS718 <b>xx-yywwwz</b> TPS718A <b>xx-yywwwz</b> TPS719 <b>xx-yywwwz</b> TPS719A <b>xx-yywwwz</b>	<ul> <li>A denotes device with rotated pin 1 orientation of wafer-chipscale package.</li> <li>XX is nominal output voltage for LDO1 (for example, 28 = 2.8V).</li> <li>YY is nominal output voltage for LDO2.</li> <li>WWW is package designator.</li> <li>Z is tape and reel quantity (R = 3000, T = 250).</li> </ul>
<b>Examples:</b> TPS71918–285DRVR TPS719185-33DRVR	XX = 18 = 1.8V, YYY = 285 = 2.85V XXX = 185 = 1.85V, YY = 33 = 3.3V DRV = 2mm x 2mm SON package Z = R = 3000 piece reel

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(2) Both outputs are programmable from 0.9V to 3.6V in 50mV increments.

(3) Output voltages from 0.9V to 3.6V in 50mV increments are available through the use of innovative factory EEPROM programming; minimum order quantities may apply. Contact factory for details and availability.

## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Over operating temperature range (unless otherwise noted). All voltages are with respect to GND.

PARAMETER	TPS718xx, TPS719xx	UNIT					
Input voltage range, V <sub>IN</sub>	-0.3 to +7.0	V					
Enable voltage range, $V_{EN1}$ and $V_{EN2}$	–0.3 to V <sub>IN</sub> + 0.3V	V					
Output voltage range, V <sub>OUT</sub>	-0.3 to +7.0	V					
Peak output current	Internally limited	ł					
Output short-circuit duration	Indefinite						
Junction temperature range, T <sub>J</sub>	-55 to +150	°C					
Storage temperature range , T <sub>STG</sub>	-55 to +150	°C					
Total continuous power dissipation, P <sub>DISS</sub>	See Dissipation Rating	s Table					
ESD rating, HBM	2	kV					
ESD rating, CDM	500	V					

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

### **DISSIPATION RATINGS**

BOARD	PACKAGE	$R_{\theta JC}$	R <sub>0JA</sub>	DERATING FACTOR ABOVE T <sub>A</sub> = +25°C	T <sub>A</sub> < +25°C	T <sub>A</sub> = +70°C	T <sub>A</sub> = +85°C
High-K <sup>(1)</sup>	DRV	20°C/W	95°C/W	10.53mW/°C	1053mW	579mW	421mW
High-K <sup>(1)</sup>	YZC	27°C/W	190°C/W	5.3mW/°C	530mW	295mW	215mW

(1) The JEDEC high-K (2s2p) board used to derive this data was a 3in × 3in, multilayer board with 1-ounce internal power and ground planes and 2-ounce copper traces on top and bottom of the board.

**EXAS INSTRUMENTS** 

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## **ELECTRICAL CHARACTERISTICS**

Over operating temperature range ( $T_J = -40^{\circ}C$  to +125°C),  $V_{IN} = V_{OUT(TYP)} + 0.5V$  or 2.7V, whichever is greater;  $I_{OUT} = 0.5$ mA,  $V_{EN1} = V_{EN2} = V_{IN}$ ,  $C_{OUT} = 1.0\mu$ F, unless otherwise noted. Typical values are at  $T_J = +25^{\circ}C$ .

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>IN</sub>	Input voltage range <sup>(1</sup>	)		2.7		6.5	V
V <sub>OUT1</sub> , V <sub>OUT2</sub>	Output voltage range	•		0.9		3.6	V
		Nominal	$T_J = +25^{\circ}C$		±2.5		mV
V <sub>OUT1</sub> , V <sub>OUT2</sub>	Output accuracy	Over V <sub>IN</sub> , I <sub>OUT</sub> , Temp	$V_{OUT} + 0.5V \le V_{IN} \le 6.5V$ 0mA $\le I_{OUT} \le 200$ mA	-3.0		+3.0	%
$\Delta V_{OUT} / \Delta V_{IN}$	Line regulation		$\label{eq:VOUT(NOM)} \begin{array}{l} V_{OUT(NOM)} + 0.5V \leq V_{IN} \leq 6.5V, \\ I_{OUT} = 5 \text{mA} \end{array}$		130		μV/V
$\Delta V_{OUT} / \Delta I_{OUT}$	Load regulation		$0mA \le I_{OUT} \le 200mA$		75		μV/mA
V <sub>DO</sub>	Dropout voltage <sup>(2)</sup> $(V_{IN} = V_{OUT(NOM)} - 0.$	1V)	I <sub>OUT</sub> = 200mA		230	400	mV
I <sub>CL</sub>	Output current limit (	per output)	$V_{OUT} = 0.9 \times V_{OUT(NOM)}$	240	340	575	mA
	Ground pin current		$I_{OUT1} = I_{OUT2} = 0.1 \text{mA}$		90	160	μΑ
I <sub>GND</sub>	Ground pin current		$I_{OUT1} = I_{OUT2} = 200 \text{mA}$		250		μΑ
	Shutdown ourront (	\ \	$V_{EN1,2} \le 0.4V, 2.7V \le V_{IN} < 4.5V, T_J = -40^{\circ}C$ to +85°C		0.3	3.0	μΑ
I <sub>SHDN</sub>	Shutdown current (I <sub>G</sub>	ND)	$V_{EN1,2} \le 0.4V, 4.5V \le V_{IN} \le 6.5V,$ $T_J = -40^{\circ}C$ to +85°C		1.8		μA
			f = 100Hz		63		dB
	Power-supply rejection	on ratio	f = 1kHz		63		dB
PSRR	$V_{IN} = 3.8V, V_{OUT} = 2$		f = 10kHz		72		dB
	I <sub>OUT</sub> = 200mA		f = 100kHz		58		dB
			f = 1MHz		44		dB
V <sub>N</sub>	Output noise voltage BW = 100Hz to 100k				$70  imes V_{OUT}$		μV <sub>RMS</sub>
T <sub>STR</sub>	Startup time <sup>(3)</sup>		$ \begin{array}{l} R_{L} = 14\Omega,  V_{OUT} = 2.8V, \\ C_{OUT} = 1.0\muF \end{array} $		160		μs
T <sub>SHUT</sub>	Shutdown time <sup>(4),(5)</sup> (TPS719xx only)		$ \begin{array}{l} R_{L} = \infty, \ C_{OUT} = 1.0 \mu F, \\ V_{OUT} = 2.8 V \end{array} $		180		μs
M	Enable high (enabled	ł)	$V_{IN} \le 5.5V$	1.2		6.5	V
V <sub>EN(HI)</sub>	(EN1 and EN2)		$5.5V < V_{IN} \le 6.5V$	1.25		6.5	V
V <sub>EN(LO)</sub>	Enable low (shutdow (EN1 and EN2)	n)		0		0.4	V
I <sub>EN</sub>	Enable pin current, e (EN1 and EN2)	nabled	EN1 = EN2 = 6.5V		0.04	1.0	μΑ
	Undervoltage lockout	t	V <sub>IN</sub> rising	2.38	2.45	2.52	V
UVLO	Hysteresis		V <sub>IN</sub> falling		150		mV
т	Thormal chutdours to	maaratura	Shutdown, temperature increasing		+160		°C
T <sub>SD</sub>	Thermal shutdown te	mperature	Reset, temperature decreasing		+140		°C
ТJ	Operating junction te	mperature		-40		+125	°C

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## **DEVICE INFORMATION**

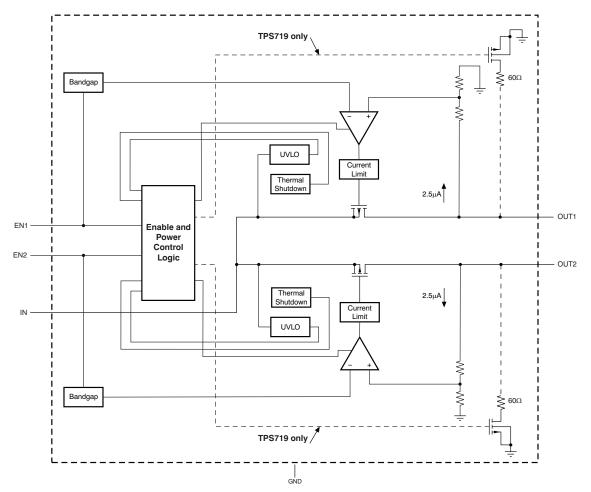


Figure 1. Functional Block Diagram

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D	RV PA SO (TOP	N-6		
	1)	·   	6	EN1
IN 2	<u>2</u> ]   G	ND	5	GND
	<u>3]</u>		4	EN2
	ZC PA -BALI (TOP	- WCS	SP	
EN1	C2 ()	C1 ()	οι	JT1
GND	В2 ()	B1 ()	IN	
EN2	A2 ()	A1 ()	OL	JT2
	TPS7 TPS7			
	ZC PA -BALI (TOP	_ WC	SP	
EN1	A1 ()	A2 ()	οι	JT1
GND	B1 ()	B2 ()	IN	
EN2	01 ()	C2 ()	οι	JT2
		18Axx 19Axx		

### PIN DESCRIPTIONS

	TPS718xx TPS719xx		TPS718Axx <sup>(1)</sup> TPS719Axx <sup>(1)</sup>	
NAME	DRV	YZC	YZC	DESCRIPTION
OUT1	1	C1	A2	Output of Regulator 1. A small ceramic capacitor (typically $\ge 1\mu F$ ) is needed from this pin to ground to assure stability.
IN	2	B1	B2	Input supply to both regulators.
OUT2	3	A1	C2	Output of Regulator 2. A small ceramic capacitor (typically $\ge 1\mu F$ ) is needed from this pin to ground to assure stability.
EN2	4	A2	C1	Enable pin for Regulator 2. Driving the Enable pin (EN2) high turns on Regulator 2. Driving this pin low puts Regulator 2 into shutdown mode, reducing operating current.
GND	5	B2	B1	Ground. DRV thermal pad should also be connected to ground.
EN1	6	C2	A1	Enable pin for Regulator 1. Driving the Enable pin (EN1) high turns on Regulator 1. Driving this pin low puts Regulator 1 into shutdown mode, reducing operating current.

(1) A option denotes devices with rotated Pin 1 orientation on Wafer Chipscale packages.

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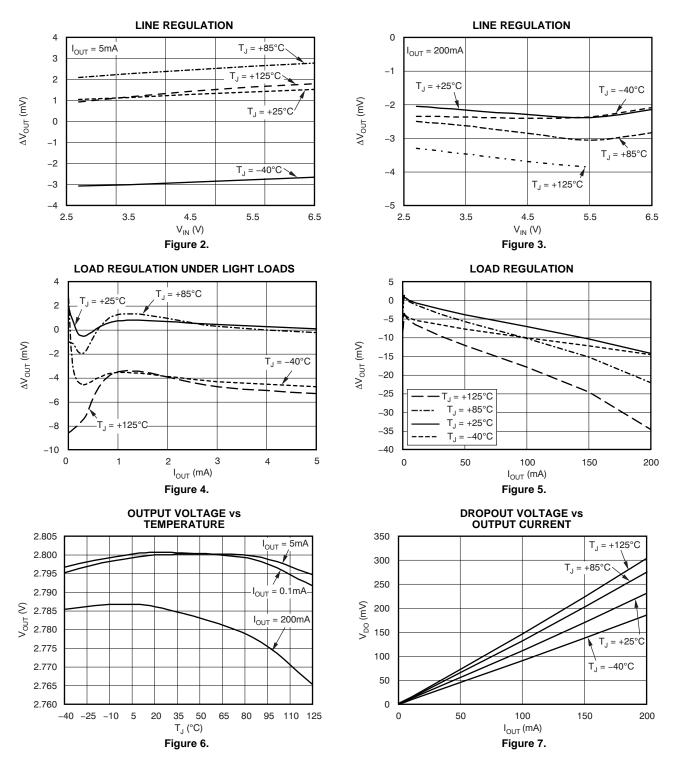
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## **TYPICAL CHARACTERISTICS**

Over operating temperature range ( $T_J = -40^{\circ}C$  to +125°C),  $V_{IN} = V_{OUT(TYP)} + 0.5V$  or 2.7V, whichever is greater;  $I_{OUT} = 0.5mA$ ,  $V_{EN1} = V_{EN2} = V_{IN}$ ,  $C_{OUT} = 1.0\mu$ F, unless otherwise noted. Typical values are at  $T_J = +25^{\circ}C$ .



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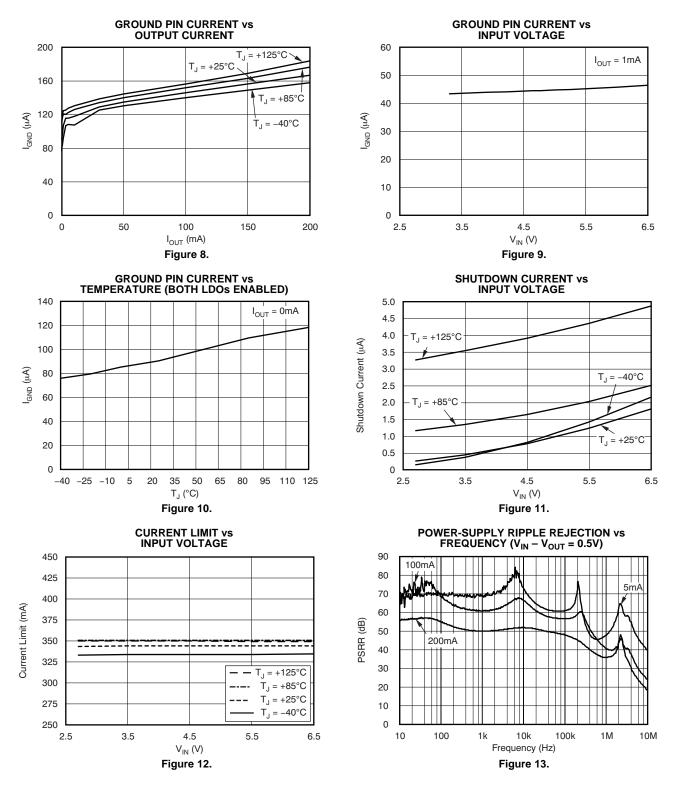
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## **TYPICAL CHARACTERISTICS (continued)**

Over operating temperature range ( $T_J = -40^{\circ}C$  to +125°C),  $V_{IN} = V_{OUT(TYP)} + 0.5V$  or 2.7V, whichever is greater;  $I_{OUT} = 0.5$ mA,  $V_{EN1} = V_{EN2} = V_{IN}$ ,  $C_{OUT} = 1.0\mu$ F, unless otherwise noted. Typical values are at  $T_J = +25^{\circ}C$ .



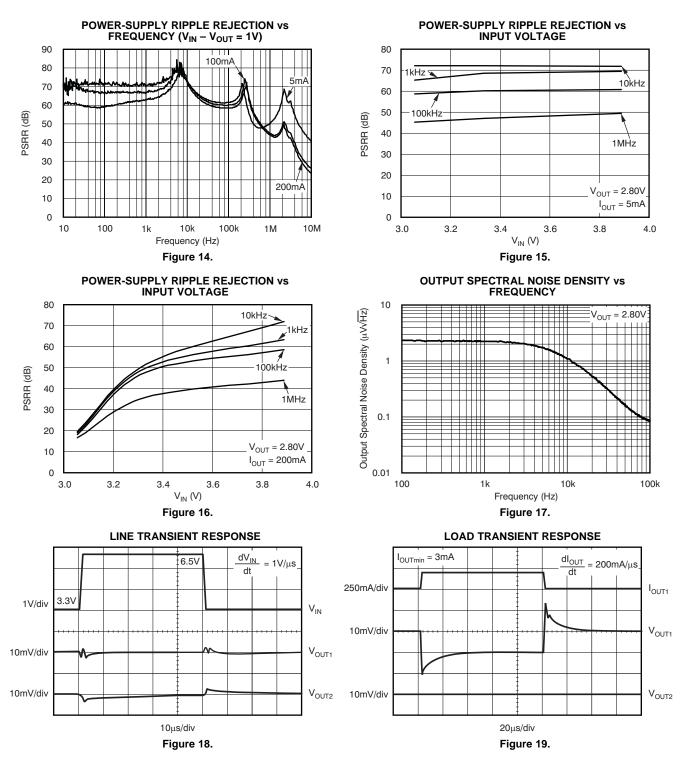
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## **TYPICAL CHARACTERISTICS (continued)**

Over operating temperature range ( $T_J = -40^{\circ}C$  to +125°C),  $V_{IN} = V_{OUT(TYP)} + 0.5V$  or 2.7V, whichever is greater;  $I_{OUT} = 0.5$ mA,  $V_{EN1} = V_{EN2} = V_{IN}$ ,  $C_{OUT} = 1.0\mu$ F, unless otherwise noted. Typical values are at  $T_J = +25^{\circ}C$ .



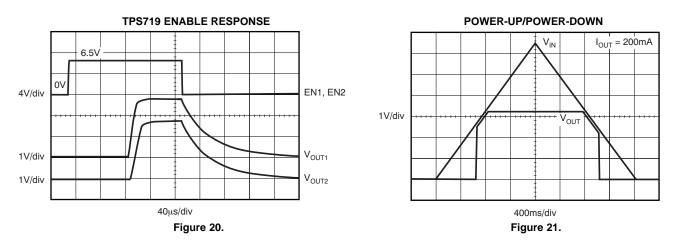
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## **TYPICAL CHARACTERISTICS (continued)**

Over operating temperature range (T<sub>J</sub> =  $-40^{\circ}$ C to  $+125^{\circ}$ C), V<sub>IN</sub> = V<sub>OUT(TYP)</sub> + 0.5V or 2.7V, whichever is greater; I<sub>OUT</sub> = 0.5mA, V<sub>EN1</sub> = V<sub>EN2</sub> = V<sub>IN</sub>, C<sub>OUT</sub> = 1.0µF, unless otherwise noted. Typical values are at T<sub>J</sub> =  $+25^{\circ}$ C.



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### **APPLICATION INFORMATION**

The TPS718xx/TPS719xx belong to a family of new generation LDO regulators that use innovative circuitry to achieve ultra-wide bandwidth and high loop gain, resulting in extremely high PSRR (up to 1MHz) at very low headroom ( $V_{IN} - V_{OUT}$ ). These features, combined with low noise, two independent enables, low ground pin current and ultra-small packaging, make this part ideal for portable applications. This family of regulators offer sub-bandgap output voltages, current limit and thermal protection, and is fully specified from -40°C to +125°C.

Figure 22 shows the basic circuit connections.

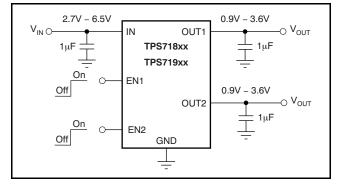


Figure 22. Typical Application Circuit

### **Input and Output Capacitor Requirements**

Although an input capacitor is not required for stability, it is good analog design practice to connect a  $0.1\mu$ F to  $1.0\mu$ F low equivalent series resistance (ESR) capacitor across the input supply near the regulator. This capacitor counteracts reactive input sources and improves transient response, noise rejection, and ripple rejection. A higher-value capacitor may be necessary if large, fast rise-time load transients are anticipated or if the device is located close to the power source. If source impedance is not sufficiently low, a  $0.1\mu$ F input capacitor may be necessary to ensure stability.

The TPS718xx/TPS719xx are designed to be stable with standard ceramic capacitors of values  $1.0\mu$ F or larger at the output. X5R- and X7R-type capacitors are best because they have minimal variation in value and ESR over temperature. Maximum ESR should be <1.0 $\Omega$ .

# Board Layout Recommendations to Improve PSRR and Noise Performance

To improve ac performance such as PSRR, output noise, and transient response, it is recommended that the board be designed with separate ground planes for  $V_{IN}$  and  $V_{OUT}$ , with each ground plane connected only at the GND pin of the device. In addition, the ground connection for the output capacitor should connect directly to the GND pin of the device. High ESR capacitors may degrade PSRR.

### **Internal Current Limit**

The TPS718xx/TPS719xx internal current limits help protect the regulator during fault conditions. During current limit, the output sources a fixed amount of current that is largely independent of output voltage. For reliable operation, the device should not be operated in a current limit state for extended periods of time.

The PMOS pass element in the TPS718xx/TPS719xx has a built-in body diode that conducts current when the voltage at OUT exceeds the voltage at IN. This current is not limited, so if extended reverse voltage operation is anticipated, external limiting to 5% of rated output current may be appropriate.

### Shutdown

The enable pin (EN) is active high and is compatible with standard and low voltage, TTL-CMOS levels. When shutdown capability is not required, EN can be connected to IN. The TPS719 with internal active output pulldown circuitry discharges the output with a time constant (t) of:

$$t = 3 \left[ \frac{60 \times R_L}{60 + R_L} \right] \times C_{OUT}$$

with:

 $R_L$  = output load resistance

 $C_{OUT}$  = output capacitance

### **Dropout Voltage**

The TPS718xx/TPS719xx use a PMOS pass transistor to achieve low dropout. When  $(V_{IN} - V_{OUT})$  is less than the dropout voltage  $(V_{DO})$ , the PMOS pass device is in its linear region of operation and the input-to-output resistance is the  $R_{DS(ON)}$  of the PMOS pass element.  $V_{DO}$  approximately scales with output current because the PMOS device behaves like a resistor in dropout.



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TPS718xx TPS719xx

As with any linear regulator, PSRR and transient response are degraded as  $(V_{IN} - V_{OUT})$  approaches dropout. This effect is shown in Figure 13 and Figure 14 in the Typical Characteristics section.

### Transient Response

As with any regulator, increasing the size of the output capacitor will reduce over/undershoot magnitude but increase duration of the transient response.

## Undervoltage Lock-Out (UVLO)

The TPS718xx/TPS719xx utilize an undervoltage lock-out circuit to keep the output shut off until internal circuitry is operating properly. The UVLO circuit has a de-glitch feature so that it typically ignores undershoot transients on the input if they are less than 50 $\mu$ s duration. On the TPS719xx, the active pulldown discharges V<sub>OUT</sub> when the device is in UVLO off condition. However, the input voltage needs to be greater than 0.8V for active pulldown to work.

### **Minimum Load**

The TPS718xx/TPS719xx are stable with no output load. Traditional PMOS LDO regulators suffer from lower loop gain at very light output loads. The TPS718xx/TPS719xx employ an innovative, low-current mode circuit under very light or no-load conditions, resulting in improved output voltage regulation performance down to zero output current.

## THERMAL INFORMATION

### **Thermal Protection**

Thermal protection disables the output when the junction temperature rises to approximately +160°C, allowing the device to cool. When the junction temperature cools to approximately +140°C the output circuitry is again enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the dissipation of the regulator, protecting it from damage due to overheating.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. For reliable operation, junction temperature should be limited to +125°C maximum. To estimate the margin of safety in a complete design heatsink), increase (including the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions. For good reliability, thermal protection should trigger at least +35°C above the maximum expected ambient condition of your particular application. This configuration produces a worst-case junction temperature of +125°C at the highest expected ambient temperature and worst-case load.

The internal protection circuitry of the TPS718xx/TPS719xx has been designed to protect against overload conditions. It was not intended to replace proper heatsinking. Continuously running the TPS718xx/TPS719xx into thermal shutdown degrades device reliability.

### **Power Dissipation**

The ability to remove heat from the die is different for each package type, presenting different considerations in the printed circuit board (PCB) layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air. Performance data for JEDEC lowand high-K boards are given in the *Dissipation Ratings* table. Using heavier copper increases the effectiveness in removing heat from the device. The addition of plated through-holes to heat-dissipating layers also improves the heatsink effectiveness.

Power dissipation depends on input voltage and load conditions. Power dissipation ( $P_D$ ) is equal to the product of the output current times the voltage drop across the output pass element ( $V_{IN}$  to  $V_{OUT}$ ), as shown in Equation 1:

$$P_{\rm D} = (V_{\rm IN} - V_{\rm OUT}) \times I_{\rm OUT}$$
(1)

### Package Mounting

Solder pad footprint recommendations for the TPS718xx/TPS719xxx are available from the Texas Instruments web site at www.ti.com.

## TPS718xx TPS719xx

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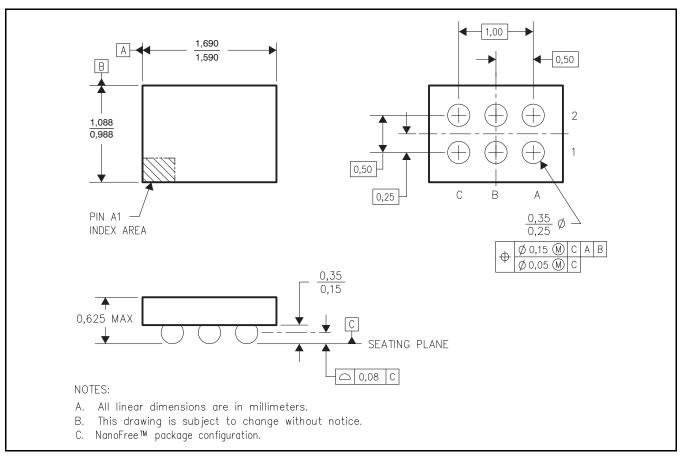


Figure 23. YZC Wafer Chip-Scale Package Dimensions (in mm)

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## **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
TPS71812-33DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVC	Samples
TPS71812-33DRVRG4	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVC	Samples
TPS71812-33DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVC	Samples
TPS71812-33DRVTG4	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVC	Samples
TPS71818-27YZCR	ACTIVE	DSBGA	YZC	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	FX	Samples
TPS71818-27YZCT	ACTIVE	DSBGA	YZC	6	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	FX	Samples
TPS71818-33DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	OEI	Samples
TPS71818-33DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	OEI	Samples
TPS71825-12DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVO	Samples
TPS71825-12DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVO	Samples
TPS71828-28YZCR	ACTIVE	DSBGA	YZC	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	FZ	Samples
TPS71828-28YZCT	ACTIVE	DSBGA	YZC	6	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	FZ	Samples
TPS71828-30DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVX	Samples
TPS71828-30DRVRG4	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVX	Samples
TPS71828-30DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVX	Samples
TPS71828-30DRVTG4	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BVX	Samples
TPS71913-28DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWP	Samples



## PACKAGE OPTION ADDENDUM

11-Apr-2013

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
TPS71913-28DRVRG4	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWP	Samples
TPS71913-28DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWP	Samples
TPS71913-28DRVTG4	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWP	Samples
TPS71918-12DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWW	Samples
TPS71918-12DRVRG4	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWW	Samples
TPS71918-12DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWW	Samples
TPS71918-12DRVTG4	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWW	Samples
TPS71918-28DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ODQ	Samples
TPS71918-28DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ODQ	Samples
TPS71921-22DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	OBW	Samples
TPS71921-22DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	OBW	Samples
TPS71926-15DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAJ	Samples
TPS71926-15DRVRG4	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAJ	Samples
TPS71926-15DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAJ	Samples
TPS71926-15DRVTG4	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAJ	Samples
TPS71928-28DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAK	Samples
TPS71928-28DRVRG4	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CAK	Samples
TPS71928-28DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	САК	Samples



## PACKAGE OPTION ADDENDUM

11-Apr-2013

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)	,	(4)	
TPS71928-28DRVTG4	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	САК	Samples
TPS719285-285DRVR	ACTIVE	SON	DRV	6	3000	TBD	Call TI	Call TI	-40 to 125	OAU	Samples
TPS719285-285DRVT	ACTIVE	SON	DRV	6	250	TBD	Call TI	Call TI	-40 to 125	OAU	Samples
TPS719285-285DSET	PREVIEW	SON	DRV	6		TBD	Call TI	Call TI	-40 to 125		
TPS71933-28DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	САН	Samples
TPS71933-28DRVRG4	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	САН	Samples
TPS71933-28DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	САН	Samples
TPS71933-28DRVTG4	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	САН	Samples
TPS71933-33DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWL	Samples
TPS71933-33DRVRG4	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWL	Samples
TPS71933-33DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWL	Samples
TPS71933-33DRVTG4	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	BWL	Samples
TPS71936-315DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CVZ	Samples
TPS71936-315DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CVZ	Samples

<sup>(1)</sup> The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.



## PACKAGE OPTION ADDENDUM

11-Apr-2013

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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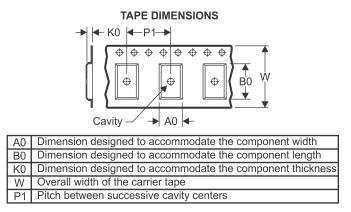
## PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS71812-33DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71812-33DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71818-33DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71818-33DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71825-12DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71825-12DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71828-30DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71828-30DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71913-28DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71913-28DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71918-12DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71918-12DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71918-28DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71918-28DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71921-22DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71921-22DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71926-15DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71926-15DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2

## PACKAGE MATERIALS INFORMATION

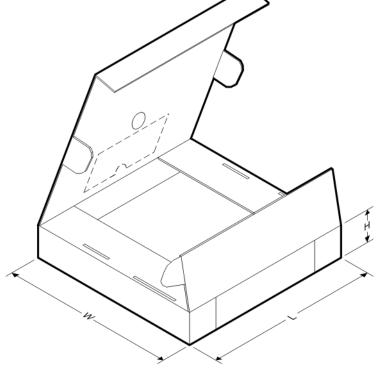


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14-Sep-2012

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS71928-28DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71928-28DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71933-28DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71933-28DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71933-33DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71933-33DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71936-315DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS71936-315DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2





*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS71812-33DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS71812-33DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS71818-33DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS71818-33DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS71825-12DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS71825-12DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS71828-30DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS71828-30DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS71913-28DRVR	SON	DRV	6	3000	203.0	203.0	35.0

## PACKAGE MATERIALS INFORMATION

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14-Sep-2012

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS71913-28DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS71918-12DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS71918-12DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS71918-28DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS71918-28DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS71921-22DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS71921-22DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS71926-15DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS71926-15DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS71928-28DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS71928-28DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS71933-28DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS71933-28DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS71933-33DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS71933-33DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS71936-315DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS71936-315DRVT	SON	DRV	6	250	203.0	203.0	35.0

## **MECHANICAL DATA**

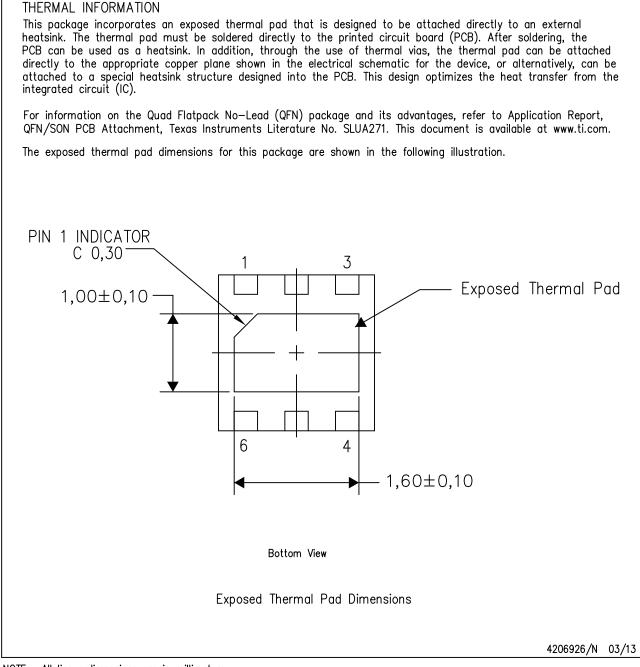


- C. Small Outline No-Lead (SON) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.



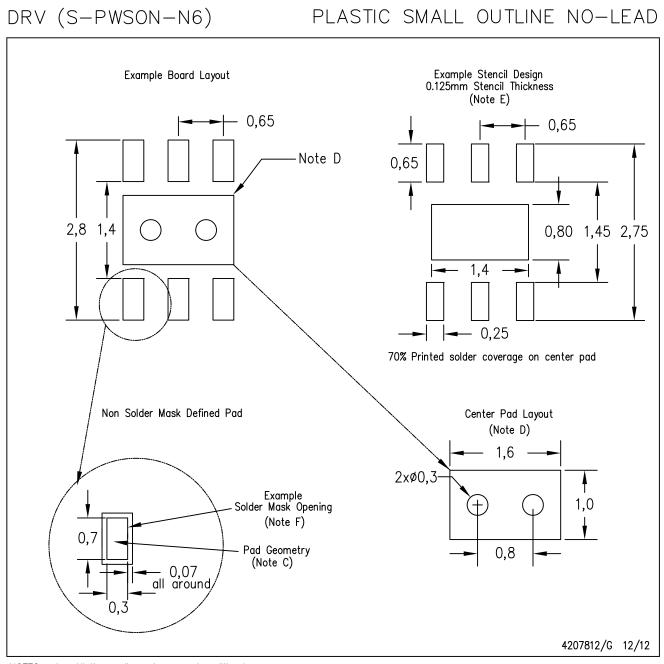
## DRV (S-PWSON-N6)

## PLASTIC SMALL OUTLINE NO-LEAD



NOTE: All linear dimensions are in millimeters





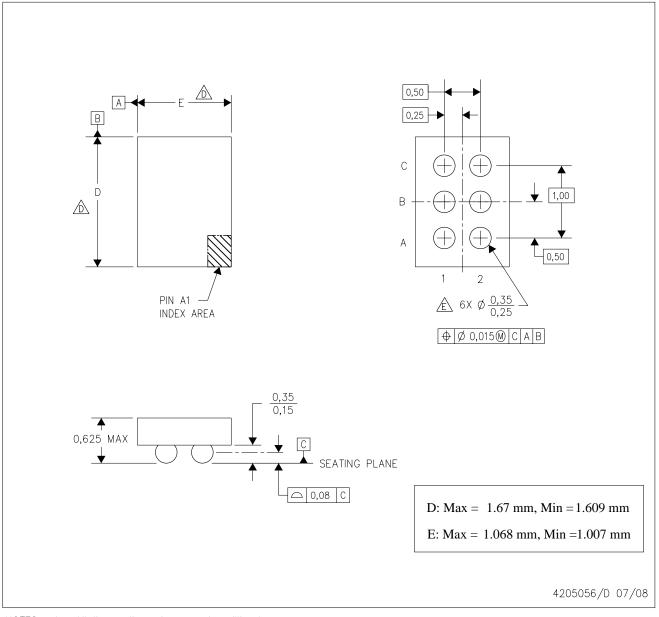
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for solder mask tolerances.





DIE-SIZE BALL GRID ARRAY



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. NanoFree™ package configuration.
  - Devices in YZC package can have dimension D ranging from 1.44 to 2.15 mm and dimension E ranging from 0.94 to 1.65 mm. To determine the exact package size of a particular device, refer to the device datasheet or contact a local TI representative.
     E. Reference Product Data Sheet for array population.
  - $3 \times 2$  matrix pattern is shown for illustration only.
  - F. This package contains lead-free balls. Refer to YEC (Drawing #4204179) for tin-lead (SnPb) balls.



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